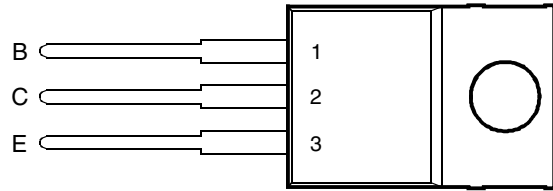




- Designed for Complementary Use with BDX53, BDX53A, BDX53B and BDX53C
- 60 W at 25°C Case Temperature
- 8 A Continuous Collector Current
- Minimum h_{FE} of 750 at 3V, 3 A

TO-220 PACKAGE
(TOP VIEW)



Pin 2 is in electrical contact with the mounting base.

MDTRACA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT
Collector-base voltage ($I_E = 0$)	BDX54	V_{CBO}	-45	V
	BDX54A		-60	
	BDX54B		-80	
	BDX54C		-100	
Collector-emitter voltage ($I_B = 0$)	BDX54	V_{CEO}	-45	V
	BDX54A		-60	
	BDX54B		-80	
	BDX54C		-100	
Emitter-base voltage		V_{EBO}	-5	V
Continuous collector current		I_C	-8	A
Continuous base current		I_B	-0.2	A
Continuous device dissipation at (or below) 25°C case temperature (see Note 1)		P_{tot}	60	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 2)		P_{tot}	2	W
Operating junction temperature range		T_j	-65 to +150	°C
Operating temperature range		T_{stg}	-65 to +150	°C
Operating free-air temperature range		T_A	-65 to +150	°C

NOTES: 1. Derate linearly to 150°C case temperature at the rate of 0.48 W/°C.
2. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.

PRODUCT INFORMATION

electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$ Collector-emitter breakdown voltage	$I_C = -100\text{ mA}$ $I_B = 0$ (see Note 3)	BDX54 BDX54A BDX54B BDX54C	-45 -60 -80 -100		V
I_{CEO} Collector-emitter cut-off current	$V_{CE} = -30\text{ V}$ $I_B = 0$ $V_{CE} = -30\text{ V}$ $I_B = 0$ $V_{CE} = -40\text{ V}$ $I_B = 0$ $V_{CE} = -50\text{ V}$ $I_B = 0$	BDX54 BDX54A BDX54B BDX54C		-0.5 -0.5 -0.5 -0.5	mA
I_{CBO} Collector cut-off current	$V_{CB} = -45\text{ V}$ $I_E = 0$ $V_{CB} = -60\text{ V}$ $I_E = 0$ $V_{CB} = -80\text{ V}$ $I_E = 0$ $V_{CB} = -100\text{ V}$ $I_E = 0$	BDX54 BDX54A BDX54B BDX54C		-0.2 -0.2 -0.2 -0.2	mA
I_{EBO} Emitter cut-off current	$V_{EB} = -5\text{ V}$ $I_C = 0$			-2	mA
h_{FE} Forward current transfer ratio	$V_{CE} = -3\text{ V}$ $I_C = -3\text{ A}$ (see Notes 3 and 4)	750			
$V_{BE(sat)}$ Base-emitter saturation voltage	$I_B = -12\text{ mA}$ $I_C = -3\text{ A}$ (see Notes 3 and 4)			-2.5	V
$V_{CE(sat)}$ Collector-emitter saturation voltage	$I_B = -12\text{ mA}$ $I_C = -3\text{ A}$ (see Notes 3 and 4)			-2	V
V_{EC} Parallel diode forward voltage	$I_E = -3\text{ A}$ $I_B = 0$			-2.5	V

NOTES: 3. These parameters must be measured using pulse techniques, $t_p = 300\ \mu\text{s}$, duty cycle $\leq 2\%$.

4. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

thermal characteristics

PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$ Junction to case thermal resistance			2.08	°C/W
$R_{\theta JA}$ Junction to free air thermal resistance			62.5	°C/W

resistive-load-switching characteristics at 25°C case temperature

PARAMETER	TEST CONDITIONS †	MIN	TYP	MAX	UNIT
t_{on} Turn-on time	$I_C = -3\text{ A}$ $I_{B(on)} = -12\text{ mA}$ $I_{B(off)} = 12\text{ mA}$		1		μs
t_{off} Turn-off time	$V_{BE(off)} = 4.2\text{ V}$ $R_L = 10\ \Omega$ $t_p = 20\ \mu\text{s}$, dc $\leq 2\%$		5		μs

† Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

TYPICAL CHARACTERISTICS

**TYPICAL DC CURRENT GAIN
VS
COLLECTOR CURRENT**

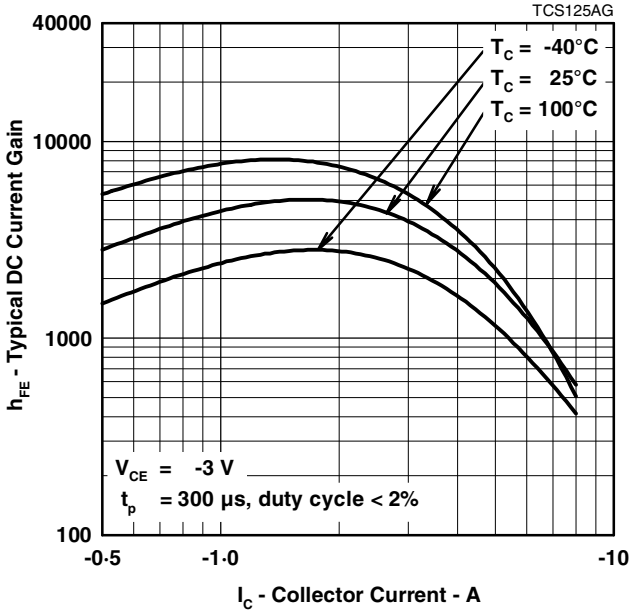


Figure 1.

**COLLECTOR-EMITTER SATURATION VOLTAGE
VS
COLLECTOR CURRENT**

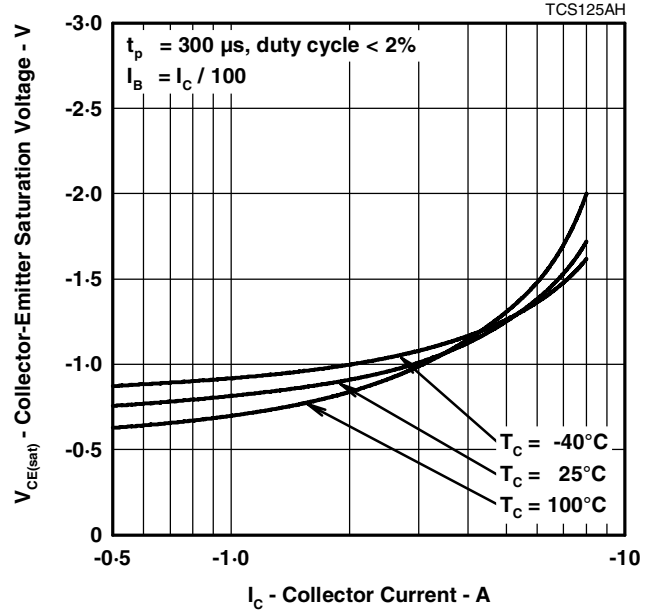


Figure 2.

**BASE-EMITTER SATURATION VOLTAGE
VS
COLLECTOR CURRENT**

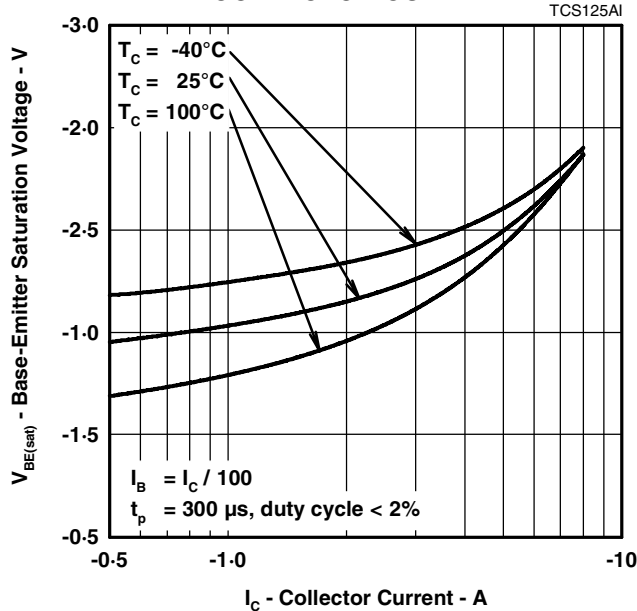


Figure 3.

PRODUCT INFORMATION

MAXIMUM SAFE OPERATING REGIONS

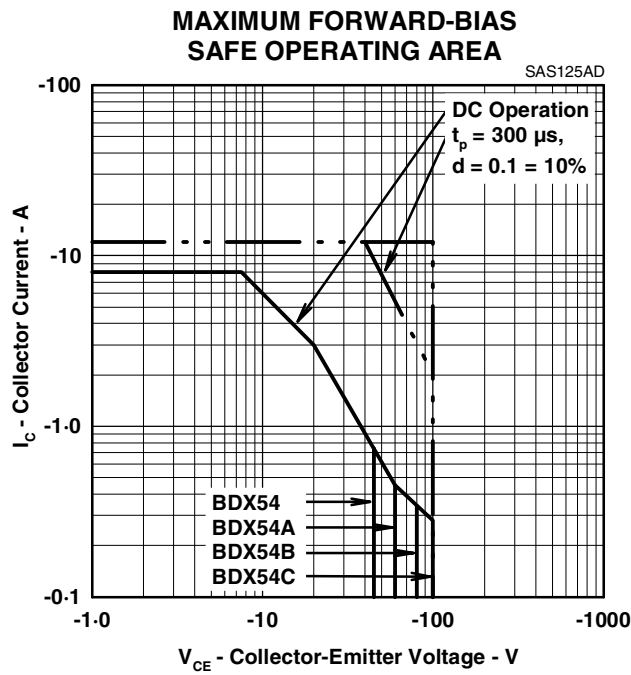


Figure 4.

THERMAL INFORMATION

**MAXIMUM POWER DISSIPATION
vs
CASE TEMPERATURE**

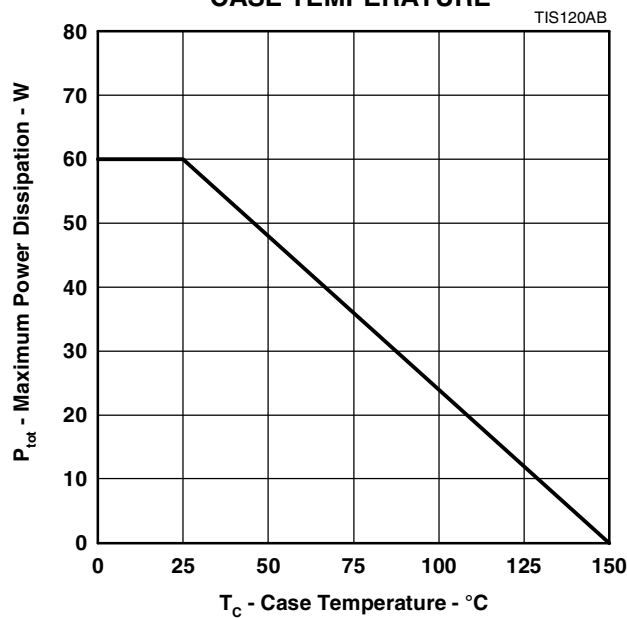


Figure 5.

PRODUCT INFORMATION

Mouser Electronics

Authorized Distributor

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